CV2384

| Specification MOS/CV2384 | SECU | RITY |
|--------------------------------------|---------------|--------------|
| Issue 3 Dated 20th July 1959 | Specification | <u>Valve</u> |
| To be read in conjunction with K1001 | UNCLASSIFIED | UNCLASSIFIED |

| In | dicates a | change | , | |
|--|---|-------------|--|--|
| TYPE OF VALVE - Silicon Junction diode | | | MARKING C.V. Number Polarity marking and where practicable factory and date code. See K1001/4 | |
| Max. Reverse Working Voltage Max. Dissipation at temperature up to 75°C Max. Dissipation at 100°C Max. Forward D.C. Current at 25°C Max. Forward D.C. Current at 100°C Max. rectified A.C. Current at 100°C Max. rectified A.C. Current at 100°C Max. reverse current at 25°C Max. reverse current at 100°C Max. reverse current at 100°C Max. Ambient Temperature rating -40°C to + 150°C | OLUTE (V) 60 (nW) 150 (nW) 100 (nA) 60 (nA) 80 (nA) 45 (vA) 10 | A A B | DIMENSIONS See specification CV 4073 MOUNTING POSITION Any | |
| CAPACITANCE (pF) Cak (max) | 5 | | | |

NOTES

- A. Mean rectified current from 50 c/s A.C. 60 volt peak into a resistive or inductive load.
- B. Applied voltage 60V
- C. At ambient temperature in excess of 75°C the ratings for dissipation, forward D.C. current and rectified A.C. current decrease linearly with temperature, reducing to zero in each case at an ambient of 150°C.

TESTS

For all purposes the tests specified in the current specification MOS/CV4073 shall apply.